Adopting a system that counts three waves in 1.5 cycle.

DESCRIPTION

The RT8H044K is a semiconductor integrated circuit designed for high-speed type earth leakage breakers. This IC includes leakage and abnormal voltage detecting functions

FEATURES

- Switchable earth leakage detection mode ; counting three waves of 1.5 cycle.
 ⇔ counting two waves of a cycle.
- Abnormal voltage detecting (neutral conductor open phase protection) function :
 - Neutral conductor open phase protection at single phase three wire system.
 - In case of no use this function, stop this function and reduction of circuit current, possible.
- High input sensitivity ; 7.5mV (DC)
- Low current dissipation ;
 - In stand-by condition : 900uA typical $(Vs = 9V, Ta = 25 \ ^{\circ}C)$
 - When SCR is ON : 620uA typical (Vs = 9V, Ta = 25 °C)
- Adopt Pulse output (thyristor drive)
- supply voltage range ; 7V to 12V
- operating ambient temperature ; -20 to 105 $^{\circ}$ C

APPLICATION

Earth leakage breaker



<Earth Leakage Detector IC>

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PIN FANCTION DESCRIPTION

Pin No.	Pin Name	Function
1	GND	Grounding
2	IREF	Connects to resistor
3	VREF	Input reference level pin.
4	ILKI	Input pin of the leakage detection circuit.
5	TRC1	Connects to capacitor for integrating output signals of the leakage input signal level discriminator. (negative)
6	TRC2	Connects to capacitor for integrating output signals of the leakage input signal level discriminator. (positive)
7	PSEL	Logic function switching pin used when detecting leakage. When the pin is grounded, counting three waves of 1.5 cycle. (neg.→pos.→neg.) When the pin is VCC, counting two waves of 1 cycle. (neg.→pos.)
8	SCRT	Output pin for drive a SCR.
9	OFFC	The pin connects to capacitor for time setting of this function.
10	TTDC	Connects to capacitor for time setting of the abnormal voltage detection circuit.
11	IBLI	Input pin of the abnormal voltage detection circuit.
12	PSAV	Switching pin used when detecting leakage ON/OFF. When the pin is grounded, enable detecting leakage. When the pin is VCC, disable detecting leakage.
13	VCC	Output pin of internal constant-voltage circuit.
14	VS	Power supply

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Symbol	Parameter	Conditions	Ratings	Unit
IS	Source current		4	mA
VS	Supply voltage		15	V
VIL	Voltage between VREF and ILKI		-1.4~1.4	V
IIL	Current between VREF and ILKI		-5~5	mA
IVREF	VREF input voltage		10	mA
IIBLI	IBLI input current		4	mA
Pd	Power dissipation	Ta≧25℃	200	mW
Κθ	Thermal derating		1.6	mW/°C
Tstg	Storage temperature	(keep dry)	<i>−</i> 40 ~ 125	°C
Topr	Operating temperature	(keep dry)	-20~105	°C

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C, unless otherwise noted)

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ELECTRICAL CHARACTERISTICS (Ta = 25°C, VS = 9Vunless otherwise noted)

0 1 1	December	Test conditions		Limits			TT . .
Symbol	Parameter			Min	Тур	Max	Unit
IS0	Supply current : in stand-by	Supply current : in stand-by PSAV=VCC			900	1040	uA
IS1	Supply current : in detecting earth leakage	PSAV=VC0	PSAV=VCC		950	1080	uA
IS2	Supply current : in detecting abnormal voltage	PSAV=VC0	C	630	900	1060	uA
IS3	Supply current : in Immediately after SCR drive	PSAV=VC0	С	430	620	730	uA
ISO'	Supply current : in stand-by	PSAV=GN	D	570	810	950	uA
IS1'	Supply current : in detecting earth leakage	PSAV=GN	D	590	840	960	uA
IS3'	Supply current : in Immediately after SCR drive	PSAV=GND		430	620	730	uA
-	ISO : Temperature dependency	Ta=-20 ~ 85℃		-	-0.12	-	%/V
VSmax	Maximum current voltage	IS=4mA		-	14.3	15.5	V
Vion	Earth leakage detection : DC input voltage	vs. VREF		-	±7.5	-	mV
IIH	ILK1 pin input bias current	VIN=VREF	7	-	2	15	nA
VO	VREF pin output voltage			-	2.6	-	V
VILKI	ILKI-VREF input clamp voltage	IILKI=±3mA		-	±1.3	-	V
VRCL	VREF-GND clamp voltage	IRCL=5mA	IRCL=5mA		5.0	-	V
EIOH	TRC1 pin "H" output current precision	VO=0V:IOH=-10.4uA		-20	-	20	%
VTH	TRC1 threshold voltage			-	2.3	-	V
ETW1	TW1 pulse width precision	C=0.01uF:TW1=2.1ms		-15	-	15	%
-	TW1 variation with ambient temperature	Ta=-20 ~ 85℃		-	-0.06	-	%/°C
EIOH	TRC2 pin "H" output current precision	VO=0V:IOH=-10uA		-20	-	20	%
VTH	TRC2 threshold voltage			-	2.3	-	V
ETW2	TW2 pulse width precision	C=0.0047uF:TW2=1.0ms 1.1m		-15	-	15	%
-	TW2 variation with ambient temperature	Ta=-20 ~ 85℃		-	-0.06	-	%/°C
VT	Total leakage detecting AC voltage	60Hz		5.2	6.5	7.8	mVrms
VBLT	Abnormal voltage detecting voltage			2.1	2.3	2.5	V
-	VBLT variation with supply voltage			-	0.01	-	%/V
-	VBLT variation with ambient temperature	Ta=-20 ~ 85°C		-	0.06	-	%/°C
IIBLT	IBLI pin input bias current	VIN=VREF		-	120	300	nA
VIBLC	IBLI-GND clamp voltage	IIN=1mA		-	7.9	-	V
EIOH	TTDC pin "H" output current precision	VO=0V:IOH=-8uA		-20	-	20	%
VTH	TTDC threshold voltage			-	2.4	-	V
ETW4	Delay time pulse width precision	C=1.0uF:TW4=280ms		-30	-	30	%
EIOH	OFFC pin "H" output current precision	VO=0V:IOH=-10uA		-20	-	20	%
VTH	OFFC threshold voltage			-	2.3	-	V
ETW3	Reset timer pulse width precision	C=0.33uF:TW3=52ms		-30	-	30	%
VOL	SCRT pin "L" output voltage	IOL=200uA		-	0.1	0.2	V
IOHc			Ta=-20°C	-200	-280	-	uA
IOHn	SCRT pin "H" output current	VO=0.8V	Ta=25°C	-100	-230	-	uA
IOHh			Ta=85°C	-70	-160	-	uA
Vsoff	IOH holding supply voltage			-	3.0	4.5	V

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I/O EQUIVALENT CIRCUIT

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<Earth Leakage Detector IC>

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Adopting a system that counts three waves in 1.5 cycle.

Timing chart

1. In detecting earth leakage

(1) Counting three waves of 1.5 cycle. (PSEL=GND)



(2) Counting two waves of a cycle. (PSEL=VCC)



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2. In detecting abnormal voltage.



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Thermal derating curve



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PRECAUTIONS FOR APPLICATION

The notes on using RT8H044K are shown below. The following precautions are only examples. Please carry out sufficient verification.

VS applied voltage

(1) IS circuit current (clamp circuit characteristics of the equivalent circuit) is as shown in TYPICAL CHARACTERISTICS figure.



Temperature characteristic ; VS clamp voltage

(2) Use of the IC by rectifying commercial power supply



- a) As Vz, be sure to use zener diode of 15V or less (not exceeding the absolute maximum rating of 12V).
- b) At high temperatures, clamp voltage decreases and ls increases. Increase of ls will be restricted at RS, however.

(3) If normal DC power supply is used, use the IC at Vs=7to10V.

Resistor of IREF pin ($R = 130k\Omega$)

Reference constant current source of the IC (for restraining fluctuations in supply voltage characteristics and ambient temperature characteristics). Since this resistor determines the characteristics of each circuit, use of high-precision resistor ($\pm 2\%$) is recommended. Although it is possible to suppress the circuit current by setting R = 150 k Ω etc., please perform sufficient verification.

Layout of printed circuit board

External noise (noise simulator etc.) may cause faulty operation of the IC. To improve the noise immunity, layout the printed circuit board so that the wiring of the external C and R is made as short as possible. Special attention should be given to the wiring of the condensers connected to Vs, Vcc and SCRT pins.

About SCRT output pin

Be careful that the voltage of SCRT output pin does not become lower than the GND level.

Change in sensitivity due to insulation deterioration

If the insulation of ZCT input pin from the high voltage part might deteriorate, improvement might be expected by connecting a resistor of about R=100k Ω between VREF pin and GND. It should be noted that the circuit current will increase at I 2.6V/R (approx.).

Clamp diode of IBLI input pin

As shown in the equivalent circuit, it is made up of series resistor and seven stages of forward diode.

- (1) At high temperatures, the drop in diode VF may decrease the clamp voltage of the pin. If the voltage approaches the reference level of the comparator (2.3V) and current leaks occur, the overvoltage detection level may slightly fluctuate. Form the detection circuit as the figure below. It is recommended that R1, R2 and VZ be set as shown below.
- (2) During excessive input, as shown above, setting should be made so that the input pin voltage becomes 4.3V or lower (to prevent the saturated comparator circuit from operating). $\cdot VZ = 4.0V$



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Reset time in reset circuit.

This circuit is designed as a timer circuit of VL = 0.7V, VH = 2.3V and $Io = 10\mu A$. When SCR is ON, the power supply route of the leakage detection and abnormal voltage detection circuits are shut off, VL does not drop to 0.7V as shown below and therefore reset time may become shorter. Set the reset time somewhat longer in advance.



Note. $t\ensuremath{\dot{\cdot}}\xspace$ time shorter than setting value

 ${}^{\bullet}\,\mbox{ln}$ the case of leakage detection : May become 10ms (50Hz) shorter

In the case of abnormal voltage detection : May become 20ms (50Hz) shorter

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Keep safety first in your circuit designs!

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